

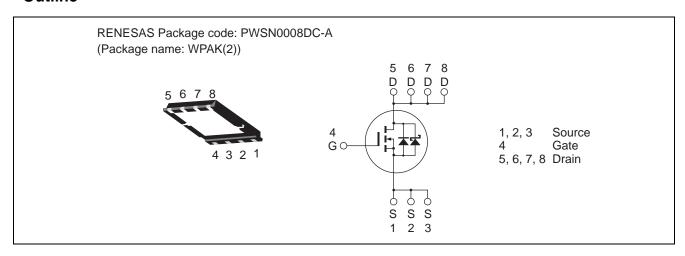
RJK0213DPA

Silicon N Channel Power MOS FET with Schottky Barrier Diode Power Switching REJ03G1942-0100 Rev.1.00 Jun 15, 2010

Features

- High speed switching
- Capable of 4.5 V gate drive
- Low drive current
- High density mounting
- Low on-resistance $R_{DS(on)} = 1.85 \text{ m}\Omega \text{ typ. (at } V_{GS} = 10 \text{ V})$
- Pb-free
- Halogen-free

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	25	V
Gate to source voltage	V _{GSS}	±20	V
Drain current	I _D	60	A
Drain peak current	I _{D(pulse)} Note1	240	A
Body-drain diode reverse drain current	I _{DR}	60	A
Avalanche current	I _{AP} Note 2	23	A
Avalanche energy	E _{AR} Note 2	66.1	mJ
Channel dissipation	Pch Note3	55	W
Channel to case thermal impedance	θch-c Note3	2.27	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 $\mu s,\,duty\,\,cycle \leq$ 1%

- 2. Value at Tch = 25°C, Rg \geq 50 Ω
- 3. $Tc = 25^{\circ}C$

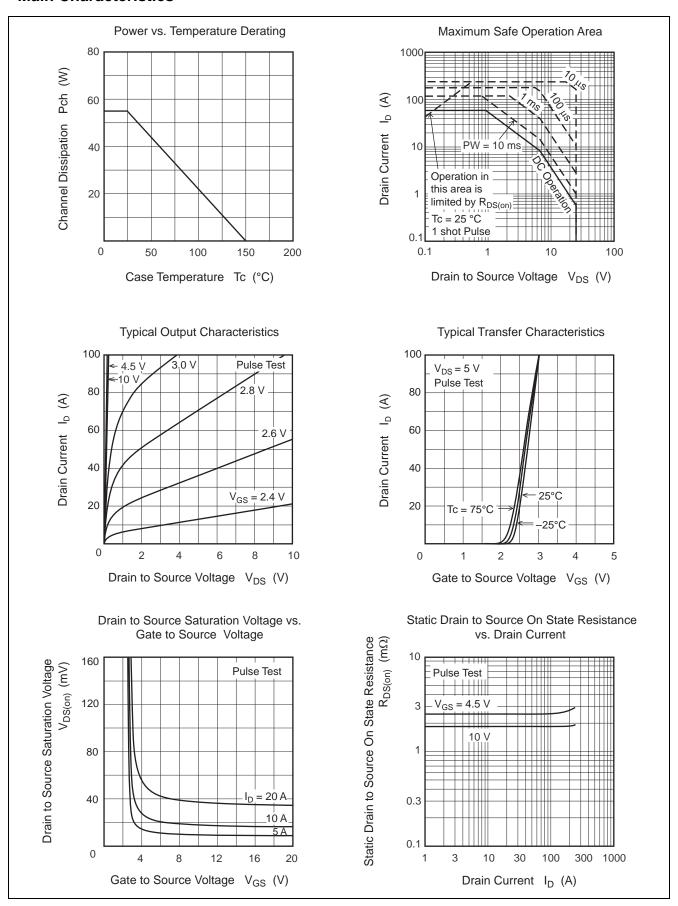
Electrical Characteristics

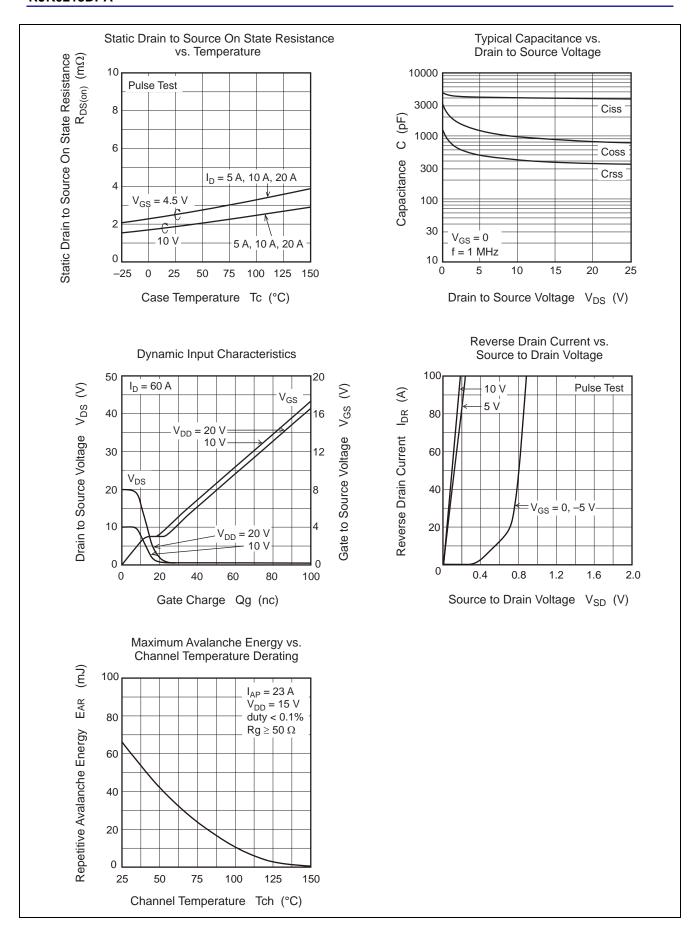
 $(Ta = 25^{\circ}C)$

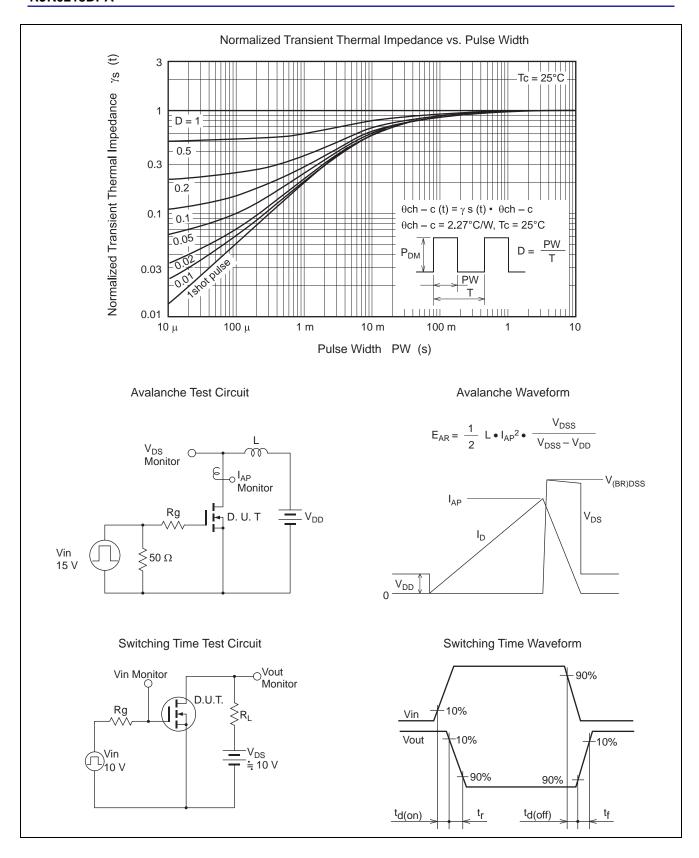
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	25	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source leak current	I_{GSS}	_	_	± 0.5	μΑ	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}	_	_	1	mA	$V_{DS} = 25 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	1.2	_	2.5	V	$V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$
Static drain to source on state	R _{DS(on)}	_	1.85	2.3	mΩ	$I_D = 30A, V_{GS} = 10 \text{ V}^{\text{Note4}}$
resistance	R _{DS(on)}	_	2.5	3.3	mΩ	$I_D = 30A$, $V_{GS} = 4.5 \text{ V}^{\text{Note4}}$
Forward transfer admittance	y _{fs}	_	110	_	S	$I_D = 30A, V_{DS} = 5 V^{Note4}$
Input capacitance	Ciss	_	4020	5630	pF	V _{DS} = 10 V
Output capacitance	Coss	_	980	_	pF	V _{GS} = 0 f = 1 MHz
Reverse transfer capacitance	Crss		420	_	pF	
Gate Resistance	Rg		1.95	3.9	Ω	
Total gate charge	Qg		26	_	nC	$V_{DD} = 10 \text{ V}$
Gate to source charge	Qgs		14	_	nC	V _{GS} = 4.5 V I _D = 60 A
Gate to drain charge	Qgd		7.3	_	nC	
Turn-on delay time	t _{d(on)}		18	_	ns	$V_{GS} = 10 \text{ V}, I_D = 30 \text{ A}$
Rise time	t _r		7.9	_	ns	$V_{DD} \cong 10 \text{ V}$
Turn-off delay time	t _{d(off)}		65	_	ns	$R_L = 0.33\Omega$
Fall time	t _f		14	_	ns	$Rg = 4.7 \Omega$
Body-drain diode forward voltage	V_{DF}		0.39	_	V	$I_F = 2 A, V_{GS} = 0^{Note4}$
Body-drain diode reverse recovery	t _{rr}	_	40	_	ns	$I_F = 60 \text{ A}, V_{GS} = 0$
time						$di_F/dt = 100 A/ \mu s$

Notes: 4. Pulse test

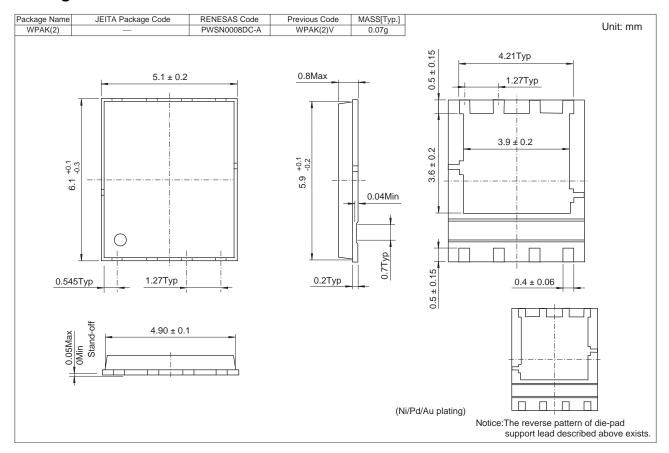
Main Characteristics







Package Dimensions



Ordering Information

Part No.	Quantity	Shipping Container
RJK0213DPA-00-J53	3000 pcs	Taping

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